Improved EMC Characteristics of PCB due to the Appropriate Via-hole Position

Li-jin Kim, Hye-jin Kim, Jae-hyun Lee

Department of Radio Science & Engineering, Chungnam National University 220, Gung-dong, Yuseong-gu, Daejeon 305-764, Korea

ljkim@cnu.ac.kr

hyejin_kim@cnu.ac.kr

jaehyun@cnu.ac.kr

Abstract— That the position of the via-hole changes the resonant characteristics of the microstrip line with a single via-hole is analyzed. Thus, the resonant characteristics of the whole PCB mat be disappeared by the appropriate choice of the position of the via-hole, and EMC performance may be improved.

Keyword— Via-hole discontinuity, Power/Ground plane resonance, PCB open edge radiation, Far-field radiation

I. INTRODUCTION

The recent trend of the digital convergence and the compact size of mobile equipments needs multilayer printed circuit board (PCB) structure and increases the complexity of internal routing of PCB. It inevitably increases the number of via-holes where the signal is transited from one layer to another in the PCB stackup. But the via-hole brings the discontinuities and so structural increases the electromagnetic compatibility (EMC) and signal integrity (SI) problems especially in the transmission of the high speed signal. Thus, a fast and accurate technique to consider the effect of via-hole discontinuity in the typical design process is needed.

Typically, the via-hole model in the PCB may be obtained by the full-wave analysis and the de-embedding techniques[1-3]. The full-wave analysis gives an accurate result, but much computational time. The via-hole modeling using a de-embedding technique gives a similar accuracy to a full-wave analysis and less computational time. When the electrical characteristics of a whole PCB having a number of via-holes is analyzed, the via-hole model obtained for a specific via-hole structure may be applied for all via-holes which have the same structure in the PCB. Thus the computational time for calculating the electrical performance of the whole PCB may be drastically reduced. However, in our recent research which analyzed the signal transmission characteristic due to the variation of the position of a viahole in the PCB, the disappearance of the resonances took place.

Therefore, in this paper the reason why the resonant frequencies are disappeared and the far-field characteristics due to that are presented.

II. THE RESONANCE

The resonance variation of the microstrip line due to the variation of the position of a single via-hole may be analyzed.

A. 4-layer PCB

Figure 1 may be considered in order to analyze the resonance of the microstrip line with a single via-hole. The via-hole is located at (x, y) and the dimension of a 4-layer PCB is $100 \times 100 \text{ mm}^2$. The characteristic impedance of the signal trace is 50 Ω and the diameter of the via-hole is 0.3 mm. The dielectric material separating each layer is FR-4 (ε_r = 44) and its thickness is 0.6 mm. Other parameters are tabulated in Table I.

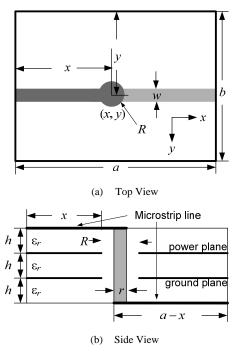


Fig. 1 Printed Circuit board with a via-hole

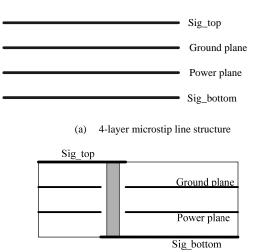
EMC'09/Kyoto

TABLE I BOARD SPEC

Spec	Value	Unit
а	100	
b	100	
h	0.6	mm
R	1	
r	0.6	
W	1	
\mathcal{E}_{r}	4.4	

B. Power/Ground Plane Resonance

In figure 2(a) which shows a miscrostrip line without a via-hole only the resonances due to the length of the line occurs. But in figure 2(b) which has a single via-hole there are some resonant points. The resonance comes from the structure in which a via-hole goes through both ground and power planes.



(b) 4-layer microstrip structure with a via-hole

Fig. 2 Power/ground plane resonance mechanism

The region between the power plane and the ground plane is regarded as a parallel plate waveguide [4]. The resonance frequency can be calculated by equation (1)

$$f_{mn} = \frac{150}{\sqrt{\varepsilon_r}} \sqrt{\left(\frac{m}{a}\right)^2 + \left(\frac{n}{b}\right)^2} \quad [\text{GHz}]$$
(1)

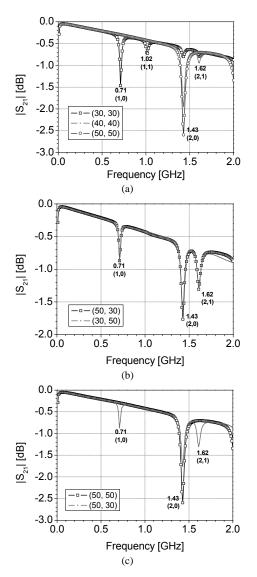
where *m* and *n* are the mode numbers in *x*-direction and *y*-direction, respectively and ε_r is the relative permittivity of the dielectric material. The calculated resonant frequencies are listed in Table II.

TABLE IIP/G plane Resonance under 2 GHz

mode (mn)	Frequency [GHz]	
10	0.71	
11	1.02	
20	1.43	
21	1.62	

C. Variations of resonant frequencies due to changes of via position

When the position of the via-hole is changed the resonant characteristic of the microstrip line with a single via-hole is varied as shown in figure 3.



EMC'09/Kyoto

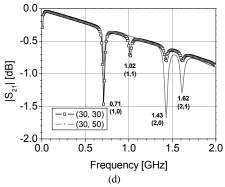


Fig. 3 Variation of resonance frequencies due to changes of via position

The comparison among the dip positions of S₂₁ magnitude for different via positions are shown in Figure 3. Figure 3(a) via-hole at (50, 50) is located at the center of the PCB and may perturb resonant modes at f_{10} , f_{01} , f_{11} , and f_{21} , and so non-perturbed resonant modes are shown at f_{20} and f_{02} . Viahole at (40, 40) is at the off centered position and may perturb resonant modes at f_{10} , f_{01} , and so resonant modes at f_{21}, f_{02}, f_{12} are shown. Via-hole at (30, 30) is located relatively far from the center and so all resonant modes are shown. In Figure 3(b) via-hole at (50, 30) is located at the center in xdirection and the off-center in y-direction, and so resonant modes at f_{01} , f_{20} , f_{02} , and f_{21} are shown. Via-hole at (30, 50) is symmetrically located relative to via-hole at (50, 30) along the diagonal direction, and so resonant modes at f_{10} , f_{20} , f_{02} , and f_{12} are shown. In Figure 3(c) at (50, 30) via-hole is symmetric in the x = 50 plane and asymmetric y = 50 plane, and so four resonant modes are shown. When via-hole is moved along the y-direction to the position at (50, 50), the xsymmetry remains and the y-symmetry occurs newly. So, resonant modes at f_{01} and f_{21} disappear. In Figure 3(d) at (30, 30) via-hole is asymmetric in the x = 50 plane and the y = 50plane, and so all resonant modes are shown. When via-hole is moved along the y-direction to via-hole at (30, 50), the xasymmetry remains and only the y-symmetry occurs newly. So, resonant modes at f_{01} , f_{11} , and f_{21} disappear.

III. THE FIELD DISTRIBUTION ANALYSIS

Each resonant mode of P/G planes in multilayer PCBs may have the different distribution of electromagnetic fields between the power plane and the ground plane. And, via-hole at the different position may give the different perturbation to the resonant field distribution.

A. Analysis of *P/G* plane field distribution with via-hole position

The field distribution between the power plane and the ground plane is analyzed at the center between the power plane and the ground plane, shown in figure 4, in order to find the reason why the variation of the resonant frequency may be brought from the different position of the via-hole. The calculated field distributions are shown in figure 5.

Figure 5 shows that if the field distribution is interrupted by the position of the via-hole then some resonant frequencies are disappeared.

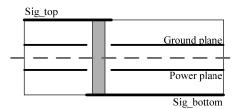
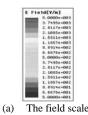


Fig. 4 The field observation plane

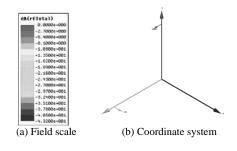


Via	Field distribution				
position	0.71 GHz	1.02 GHz	1.43 GHz	1.62 GHz	
(x, y)	(1,0)	(1,1)	(2,0)	(2,1)	
Non-via	l'				
(30, 30)		3	$\langle \rangle$	7	
(30, 50)			$\langle \rangle$	ĘĊ	
(40, 40)		70	$\langle \rangle$	De	
(50, 30)		A	$\langle\!\langle\rangle\!\rangle$		
(50, 50)	0	0	\diamond		

Fig. 5 The field distribution in P/G plane

B. Far-field Radiation Pattern

The figure 6 shows that the far-field radiation patterns are calculated at the resonant frequencies. The intensity of the radiated far-field is increased at the resonant frequency.



EMC'09/Kyoto

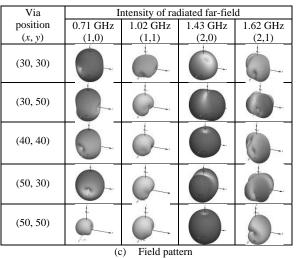


Fig 6. Far-field radiation pattern

IV. CONCLUSION

That the position of the via-hole changes the resonant characteristics of the microstrip line with a single via-hole is analyzed. Thus, the resonant characteristics of the whole PCB mat be disappeared by the appropriate choice of the position of the via-hole, and EMC performance may be improved.

ACKNOWLEDGMENTS

This research was supported by the MIC (Ministry of Information and Communication), Korea, under the ITRC (Institute for Information Technology Advancement) (IITA-2008-(C1090-0603-0034))

REFERENCES

- G. Antonini, A.C. Scogna, and A. Orlandi, "S-parameters characterization of through, blind and buried via holes," IEEE Transactions Mobile Computing., vol. 2, pp. 174–184, April–June 2003.
- [2] G. Antonini, A.C. Scogna, and A. Orlandi, "Characterization of via holes discontinuities by means of numerical de-embedding," IEEE International Symposium on Electromagnetic Compatibility 2003, vol. 2, pp. 591–596, 18– 22 Aug. 2003.
- [3] G. Antonini, M. Lai, A. Orlandi, and V. Ricchiuti, "Characterization of via holes on printed circuit boards", *Proceedings of the 8th IEEE Workshop on Signal Propagation on Interconnects*, pp. 211–214, 9–12 May 2004.
- [4] David M. Porzar, "Microwave Engineering," New York: Wiley-Intersciences.2005, pp.278-282.